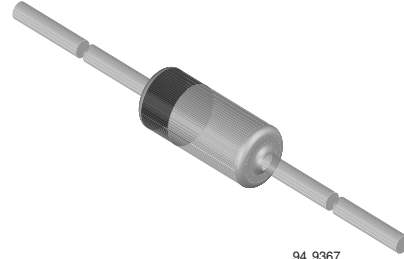


Fast Switching Diode

Features

- Fast switching speed
- High reliability
- High conductance
- For general purpose switching applications



94 9367

Mechanical Data

Case: DO-35 Glass Case

Weight: approx. 130 mg

Packaging Codes/Options:

TR / 10 k per 13 " reel (52 mm tape), 50 k/box

TAP / 10 k per Ammopack (52 mm tape), 50 k/box

Parts Table

Part	Type differentiation	Ordering code	Remarks
1N914	$V_{RRM} = 75 \text{ V}$	1N914-TAP / 1N914-TR	Ammopack / Tape and Reel

Absolute Maximum Ratings

$T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Non repetitive peak reverse voltage		V_{RM}	100	V
Repetitive peak reverse voltage		V_{RRM}	75	V
Working peak reverse voltage		V_{RWM}	75	V
DC blocking voltage		V_R	75	V
RMS Reverse voltage		$V_{R(RMS)}$	53	V
Forward current		I_F	300	mA
Average rectified current	half wave rectification with resistive load and $f > 50 \text{ MHz}$	I_{FAV}	200	mA
Non repetitive peak forward surge current	$t = 1 \text{ s}$	I_{FSM}	1	A
	$t = 1 \text{ } \mu\text{s}$	I_{FSM}	4	A
Power dissipation	$l = 4 \text{ mm}$, $T_L 25 \text{ }^\circ\text{C}$	P_d	500	mW

Thermal Characteristics

$T_{amb} = 25 \text{ }^\circ\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Junction ambient	$l = 4 \text{ mm}$, $T_L = \text{constant}$	R_{thJA}	300	K/W
Operating and storage temperature range		T_j, T_{stg}	-65 to +175	$^\circ\text{C}$

Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Test condition	Symbol	Min	Typ.	Max	Unit
Forward voltage	$I_F = 10\text{ mA}$	V_F			1	V
Breakdown Voltage	$I_R = 100\text{ }\mu\text{A}$	V_R	100			V
Peak reverse current	$V_R = 75\text{ V}$	I_R			5.0	μA
	$V_R = 20\text{ V}, T_j = 150\text{ }^{\circ}\text{C}$	I_R			50	μA
	$V_R = 20\text{ V}$	I_R			25	nA
Diode capacitance	$V_R = 0, f = 1\text{ MHz}$	C_D			4	pF
Reverse recovery time	$I_F = 10\text{ mA}$ to $I_R = 1\text{ mA}$, $V_R = 6\text{ V}, R_L = 100\text{ }\Omega$	t_{rr}			4	ns

Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

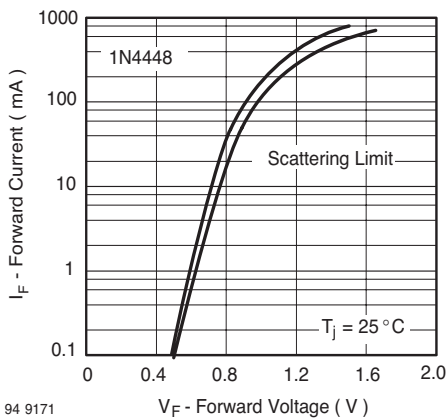


Figure 1. Forward Current vs. Forward Voltage

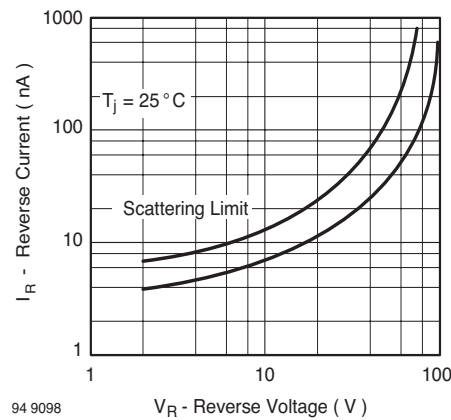


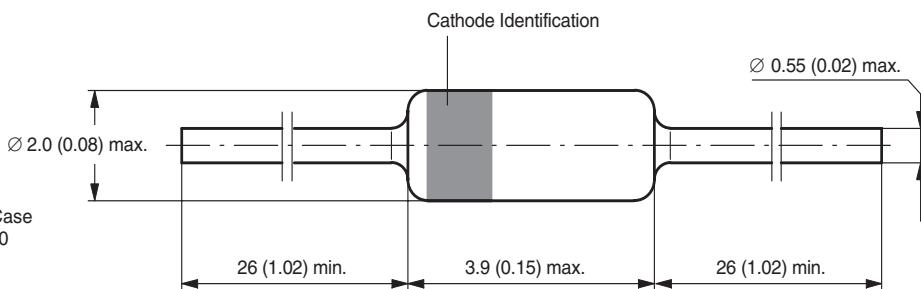
Figure 2. Reverse Current vs. Reverse Voltage

Package Dimensions in mm (Inches)

technical drawings according to DIN specifications

94 9366

Standard Glass Case
54 A 2 DIN 41880
JEDEC DO 35



Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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